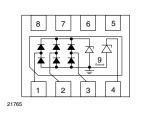
Vishay Semiconductors

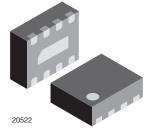
RoHS COMPLIANT

<u>GREEN</u> (5-2008)**

USB-OTG BUS-Port ESD-Protection for V_{BUS} = 12 V



SHA



MARKING (example only)

•YXX

Dot = pin 1 marking

YY = type code (see table below) XX = date code

FEATURES

- Ultra compact LLP1713-9L package
- Low package height < 0.6 mm
- 3-line USB ESD-protection with max. working range = 5.5 V
- + V_{BUS} protection with 12 V working range
- Low leakage current
- Low load capacitance $C_D = 0.7 \text{ pF}$
- ESD-protection acc. IEC 61000-4-2 ± 12 kV contact discharge
 - ± 15 kV air discharge
- Surge current acc. IEC 61000-4-5 $I_{PP} > 3 A$
- e4 precious metal (e.g. Ag, Au, NiPd, NiPdAu) (no Sn)
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

ORDERING INFORMATION				
DEVICE NAME	DEVICE NAME ORDERING CODE		MINIMUM ORDER QUANTITY	
VBUS053BZ-HNH	VBUS053BZ-HNH-G-08	3000	15 000	

PACKAGE DATA						
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
VBUS053BZ-HNH	LLP1713-9L	к	3.7 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals

ABSOLUTE MAXIMUM RATINGS VBUS053BZ-HNH						
RATING	TEST CONDITIONS	SYMBOL	VALUE	UNIT		
Data line D+, D-, ID: Pin 1, 2	and 3 to ground (pin 9)					
Peak pulse current	acc. IEC 61000-4-5, t_p = 8/20 µs/single shot	I _{PPM}	3	А		
Peak pulse power	acc. IEC 61000-4-5, $t_P = 8/20 \ \mu s/single shot$	P _{PP}	36	W		
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	M	± 12	kV		
	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 15	kV		
V _{BUS} : Pin 4 to ground (pin 9)						
Peak pulse current	acc. IEC 61000-4-5, $t_p = 8/20 \ \mu s/single shot$	I _{PPM}	8	А		
Peak pulse power	acc. IEC 61000-4-5, $t_P = 8/20 \ \mu s/single shot$	P _{PP}	240	W		
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	M	± 30	kV		
	Air discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	± 30	kV		
Operating temperature	Junction temperature	T _J - 40 to + 125		°C		
Storage temperature		T _{stg}	- 55 to + 150	°C		

** Please see document "Vishay Material Category Policy": <u>www.vishay.com/doc?99902</u>

Vishay Semiconductors USB-OTG BUS-Port ESD-Protection

for $V_{BUS} = 12 V$



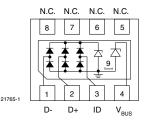
APPLICATION NOTE

The VBUS053BZ-HNH is intended as an ESD-protection and transient voltage suppressor for one USB-OTG port.

The LLP1713-9L package contains two separate dies which are mounted on a common ground plane (pin 9). The high-speed data lines D-, D+ and ID, are connected to any of the pins no. 1 to 3. As long as the signal voltage on the data lines is between the ground- and the 5 V working range, the low capacitance PN-diodes offer a very high isolation to ground and to the other data lines. But as soon as any transient signal like an ESD-signal, exceeds this working range of 5 V in either the positive or negative direction, one of the PN-diodes gets into the forward mode and clamps the transient either to ground or to the avalanche break through level.

An extra avalanche diode (separate die) clamps the supply line voltage (V_{BUS} at pin 4) above the 12 V working range to ground (pin 9).

Due to the "two die construction" the V_{BUS} line has a very high isolation to the data lines. In case of a destructive transient signal, i.e. coming from a charger, the data lines will not be influenced.



Remark:

The input pins no. 1, 2 and 3 are symmetrical. Each of the data signals D-, D+ and ID can be connected to pin 1, 2 or 3.

PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Data line D+, D-, ID: Pin 1, 2 a	and 3 to ground (pin 9)					
Protection paths	Number of lines which can be protected	N _{channel}	-	-	3	lines
Reverse working voltage	at I _R = 0.1 μA	V _{RWM}	5.5	-	-	V
	at $V_R = V_{RWM} = 3.3 \text{ V}; \text{ T} = 65 ^{\circ}\text{C}$	I _R	-	-	0.0085	μA
Reverse current	at $V_R = V_{RWM} = 5 V$	I _R	-	-	1	μA
Forward voltage	at I _F = 15 mA	V _F	0.7	-	1.2	V
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	6.5	-	10	V
Reverse clamping voltage	at I _{PP} = 1 A, acc. IEC 61000-4-5; T = 25 °C	V _C	-	10	12	V
	at I _{PP} = 3 A, acc. IEC 61000-4-5; T = 25 °C	V _C	-	15	18	V
Forward clamping voltage	at I _F = 3 A, acc. IEC 61000-4-5;	V _F	-	3.4	4.1	V
Capacitance	Test pin at V _R = 0 V; any other I/O pin at V _R = 3.3 V, f = 1 MHz	C _D	-	0.7	1	pF
Symmetry	Difference of the line capacitance	dC _D	-	-	0.1	pF
Line to line capacitance	Among pins 1, 2 and 3 at $V_R = 0 V$; f = 1 MHz	C _{DD}	-	0.35	0.5	pF
V _{BUS} : Pin 4 to ground (pin 9)	•				•	
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines
Reverse working voltage	at I _R = 100 nA	V _{RWM}	12	-	-	V
Reverse current	at $V_R = V_{RWM} = 12 V$	I _R	-	-	100	nA
Forward voltage	at I _F = 10 mA	V _F	0.6	0.75	0.9	V
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	15	-	18	V
Reverse clamping voltage	at I _{PP} = 1 A, acc. IEC 61000-4-5; T = 25 °C	V _C	-	17.5	20	V
	at I _{PP} = 8 A, acc. IEC 61000-4-5; T = 25 °C	V _C	-	25	30	V
Forward clamping voltage	at I _F = 8 A, acc. IEC 61000-4-5;	V _F	-	-	2.2	V
Capacitance	at $V_B = 0$ V; f = 1 MHz	CD	-	70	85	pF

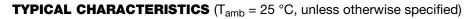
Note

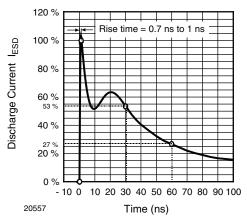
• Ratings at - 40 °C to 85 °C, ambient temperature unless otherwise specified

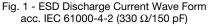


VBUS053BZ-HNH

USB-OTG BUS-Port ESD-Protection Vishay Semiconductors for $V_{BUS} = 12 V$







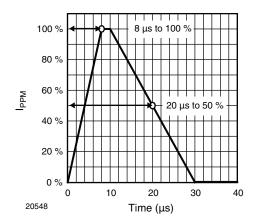


Fig. 2 - 8/20 µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

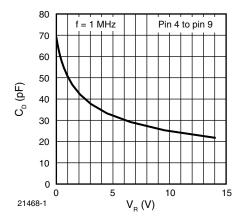


Fig. 3 - Typical Capacitance C_D vs. Reverse Voltage V_R

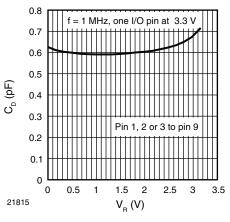


Fig. 4 - Typical Capacitance C_D vs. Reverse Voltage V_R

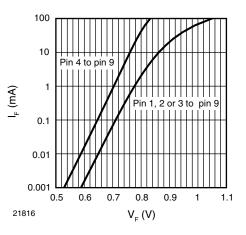


Fig. 5 - Typical Forward Current I_F vs. Forward Voltage V_F

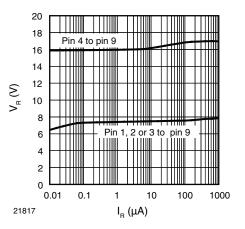


Fig. 6 - Typical Reverse Voltage V_R vs. Reverse Current I_R

VBUS053BZ-HNH

Vishay Semiconductors USB-OTG BUS-Port ESD-Protection

for $V_{BUS} = 12 V$

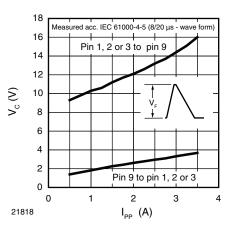
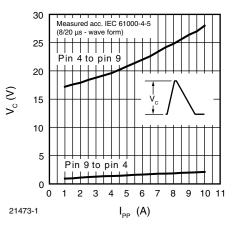


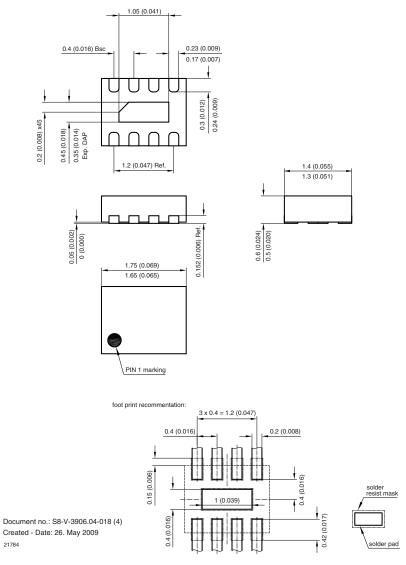
Fig. 7 - Typical Peak Clamping Voltage V_C vs. Peak Pulse Current I_{PP}



SHA

Fig. 8 - Typical Peak Clamping Voltage V_C vs. Peak Pulse Current I_{PP}







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